N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
20	0.033 at V_{GS} = 4.5 V	4.9
	0.040 at V_{GS} = 2.5 V	4.4
	0.051 at V_{GS} = 1.8 V	3.9

FEATURES

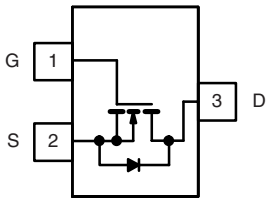
- **Halogen-free According to IEC 61249-2-21 Available**
- TrenchFET® Power MOSFET
- ESD Protected: 3000 V

Pb-free
RoHS COMPLIANT
HALOGEN FREE Available

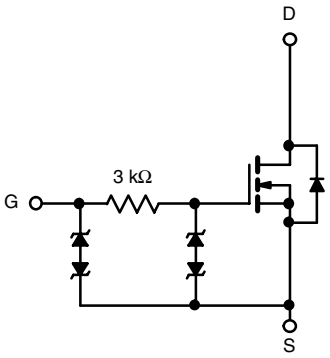
APPLICATIONS

- LI-Ion Battery Protection

TO-236
(SOT-23)



Top View
Si2314EDS (C4)*
*Marking Code



N-Channel

Ordering Information: Si2314EDS-T1-E3 (Lead (Pb)-free)
Si2314EDS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted					
Parameter		**Symbol**	**5 s**	**Steady State**	**Unit**
Drain-Source Voltage		V_{DS}	20		V
Gate-Source Voltage		V_{GS}	± 12		
Continuous Drain Current (T_J = 150 °C)[a]	T_A = 25 °C	I_D	4.9	3.77	A
	T_A = 70 °C		3.9	3.0	
Pulsed Drain Current[b]		I_{DM}	15		
Avalanche Current[b]	L = 0.1 mH	I_{AS}	15		
Single Avalanche Energy		E_{AS}	11.25		mJ
Continuous Source Current (Diode Conduction)[a]		I_S	1.0		A
Power Dissipation[a]	T_A = 25 °C	P_D	1.25	0.75	W
	T_A = 70 °C		0.80	0.48	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		**Symbol**	**Typical**	**Maximum**	**Unit**
Maximum Junction-to-Ambient[a]	t ≤ 5 s	R_{thJA}	75	100	°C/W
	Steady State		120	166	
Maximum Junction-to-Foot	Steady State	R_{thJF}	40	50	

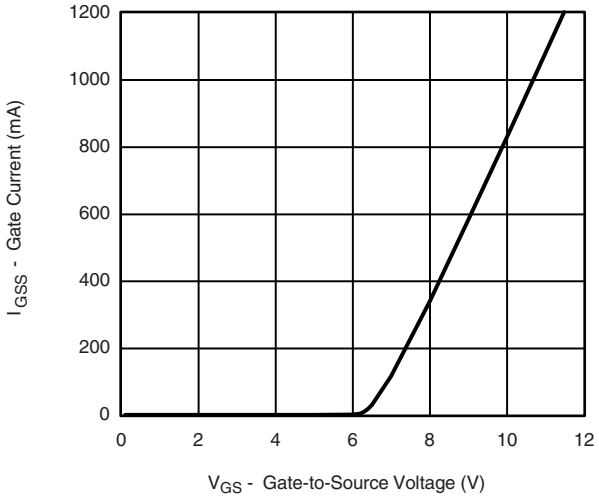
Notes:
a. Surface Mounted on 1" x 1" FR4 board.
b. Pulse width limited by maximum junction temperature.

SPECIFICATIONS T_A = 25 °C, unless otherwise noted						
Parameter	**Symbol**	**Test Conditions**	**Limits**			**Unit**
			Min.	**Typ.**	**Max.**	
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	20			V
Gate-Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	0.45		0.95	
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 4.5 V			± 1.5	µA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 20 V, V_{GS} = 0 V			1	
		V_{DS} = 20 V, V_{GS} = 0 V, T_J = 70 °C			75	
On-State Drain Current[a]	$I_{D(on)}$	$V_{DS} \geq$ 10 V, V_{GS} = 4.5 V	15			A
Drain-Source On-Resistance[a]	$R_{DS(on)}$	V_{GS} = 4.5 V, I_D = 5.0 A		0.027	0.033	Ω
		V_{GS} = 2.5 V, I_D = 4.5 A		0.033	0.040	
		V_{GS} = 1.8 V, I_D = 4.0 A		0.042	0.051	
Forward Transconductance[a]	g_{fs}	V_{DS} = 15 V, I_D = 5.0 A		40		S
Diode Forward Voltage	V_{SD}	I_S = 1.0 A, V_{GS} = 0 V		0.8	1.2	V
Dynamic[b]						
Total Gate Charge	Q_g	V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 5.0 A		11.0	14.0	nC
Gate-Source Charge	Q_{gs}			1.5		
Gate-Drain Charge	Q_{gd}			2.1		
Switching						
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 10 V, R_L = 10 Ω $I_D \cong$ 1.0 A, V_{GEN} = 4.5 V, R_g = 6 Ω		0.53	0.8	µs
Rise Time	t_r			1.4	2.2	
Turn-Off Delay Time	$t_{d(off)}$			13.5	20	
Fall Time	t_f			5.9	9	
Source-Drain Reverse Recovery Time	t_{rr}	I_F = 1.0 A, dI/dt = 100 A/µs		13	25	ns

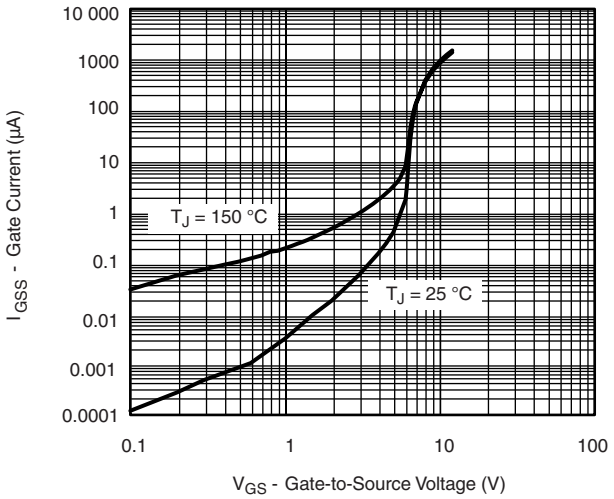
Notes:
a. Pulse test: PW ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

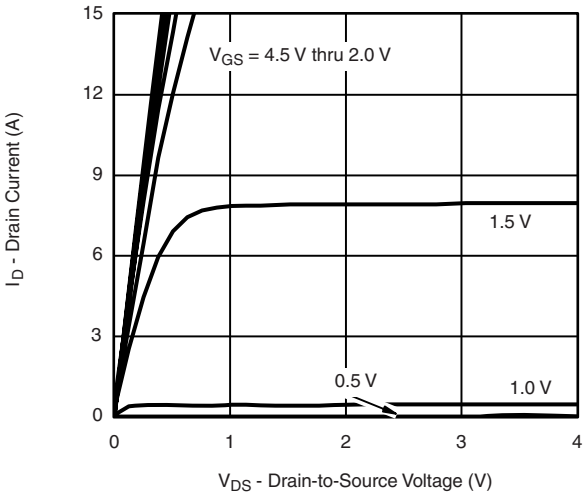


Gate-Current vs. Gate-Source Voltage

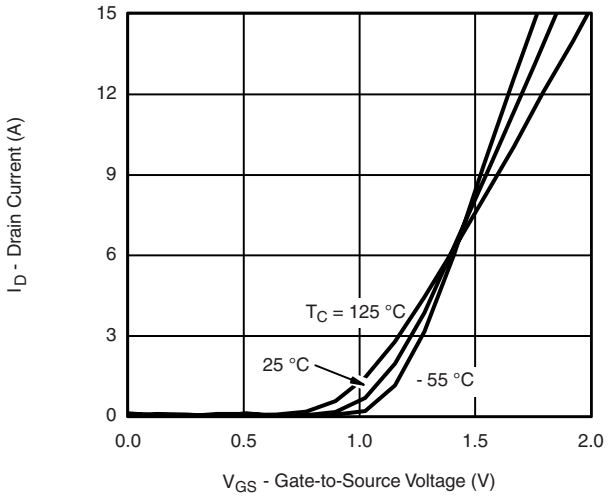


Gate Current vs. Gate-Source Voltage

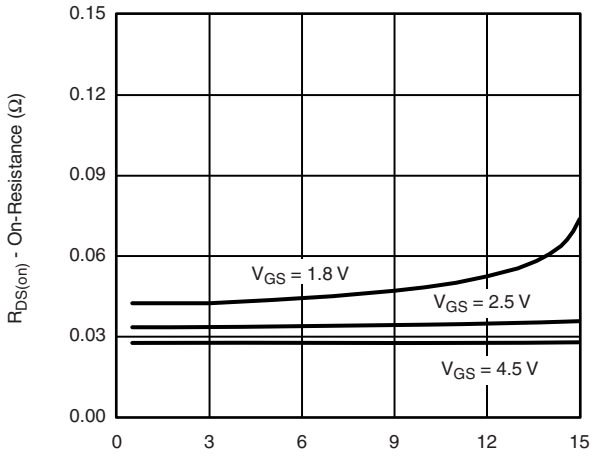
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



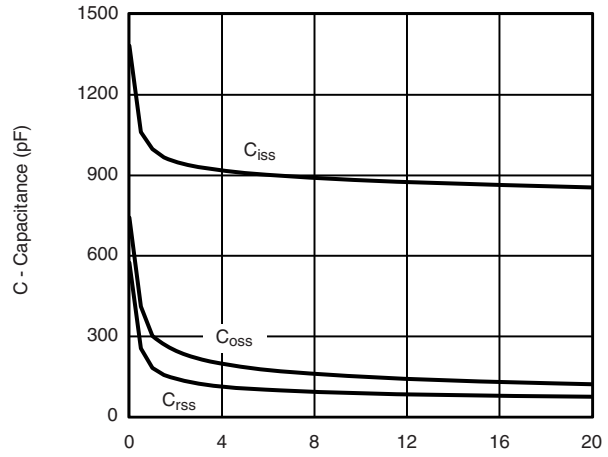
Output Characteristics



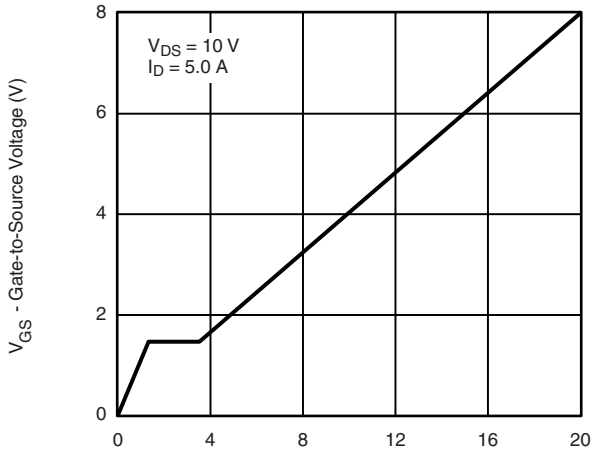
Transfer Characteristics



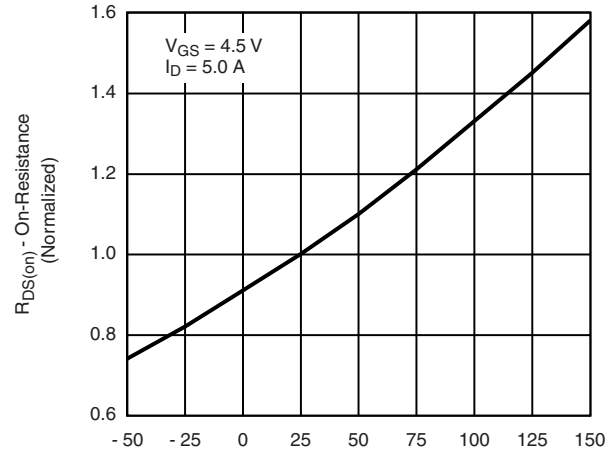
On-Resistance vs. Drain Current



Capacitance

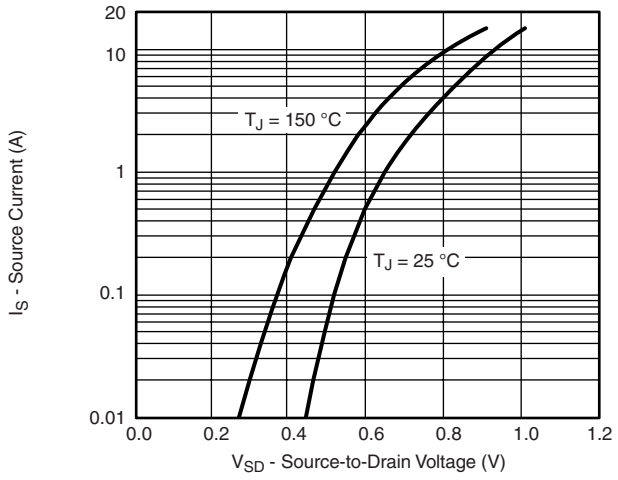


Gate Charge

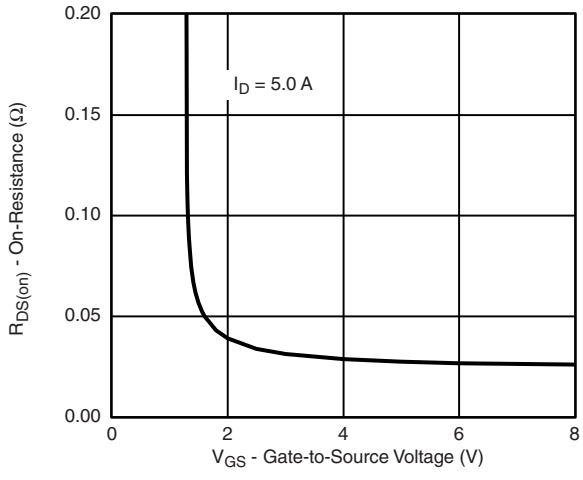


On-Resistance vs. Junction Temperature

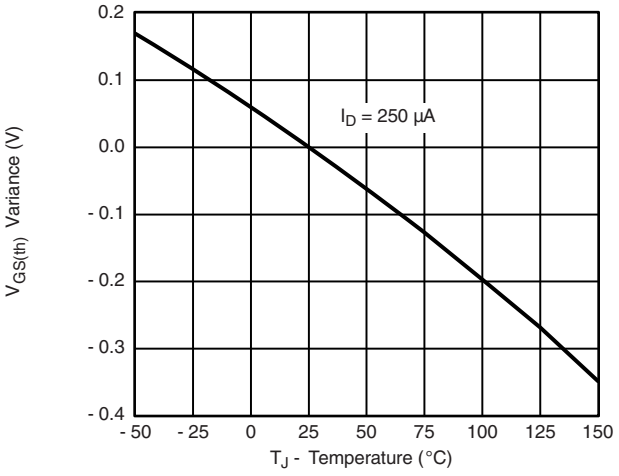
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



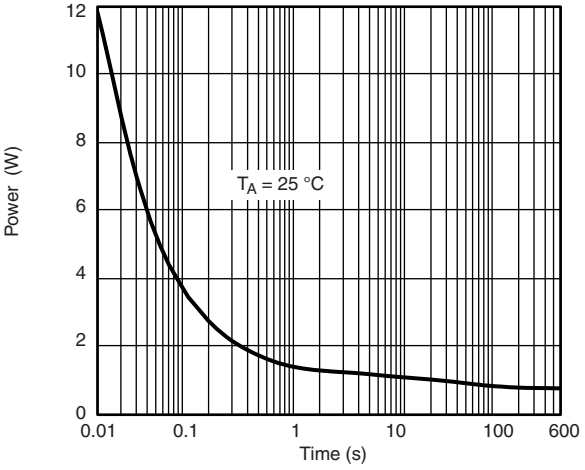
Source-Drain Diode Forward Voltage



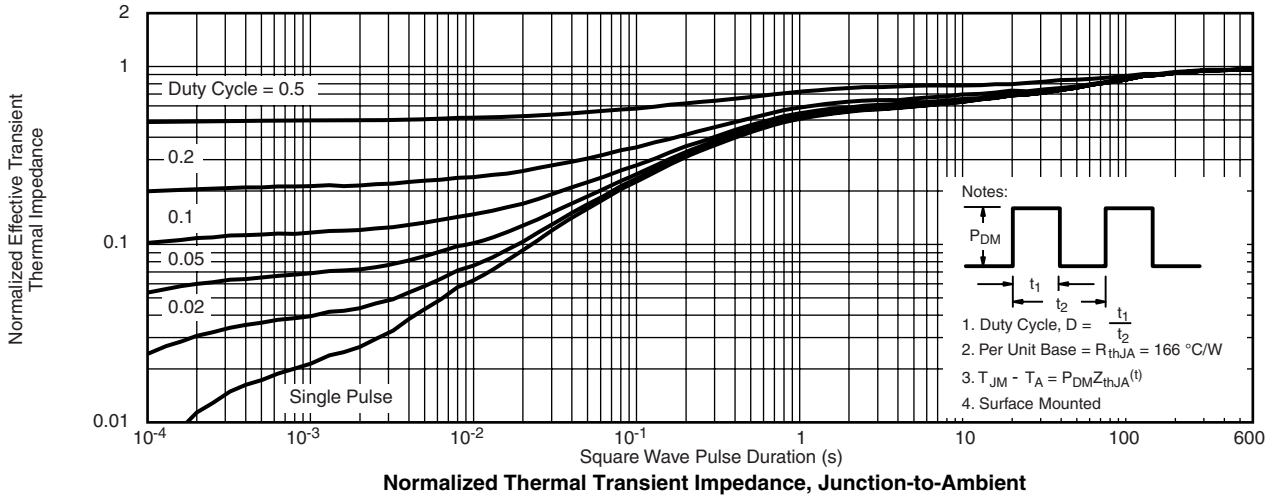
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



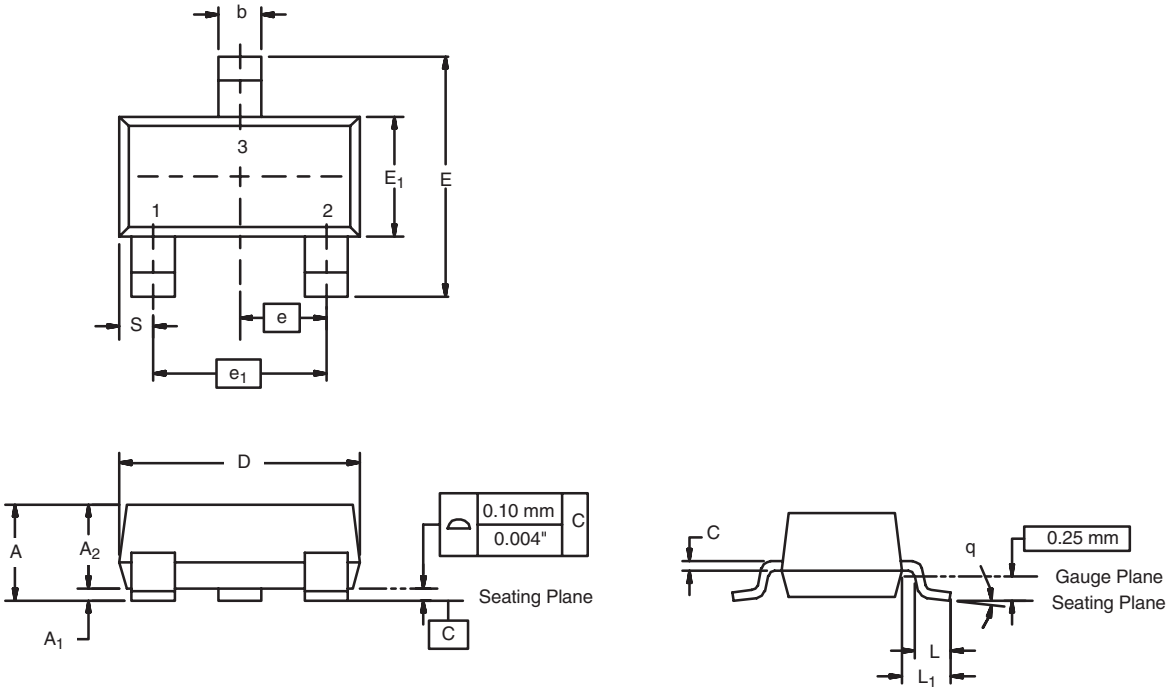
Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

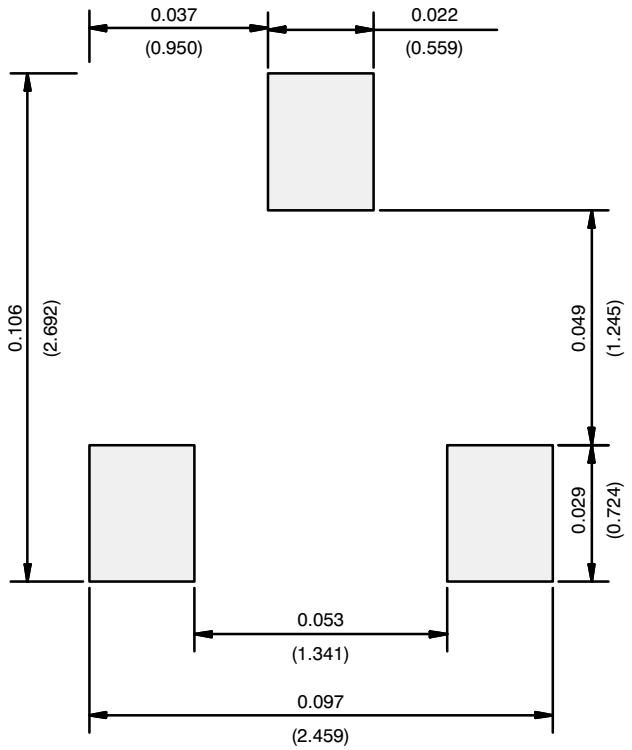
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SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A_1	0.01	0.10	0.0004	0.004
A_2	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E_1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e_1	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L_1	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°
ECN: S-03946-Rev. K, 09-Jul-01 DWG: 5479				

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

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APPLICATION NOTE

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